Power Inductor

HPC4018NF-SERIES-M

	ECN HISTORY LIST									
REV	DATE	DESCRIPTION	APPROVED	CHECKED	DRAWN					
1.0	16/03/07	新 發 行	楊祥忠	詹偉特	孔妍暄					
1.1	16/05/26	增加 2R2、150、330、470 感值特性	楊祥忠	詹偉特	孔妍暄					
備										
註										
μт.										

Power Inductor

HPC4018NF-SERIES-M

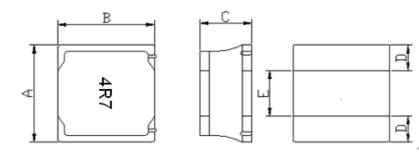
1. Features

- 1. This specification applies Low Profile Power Inductors.
- 2. 100% Lead(Pb) & Halogen-Free and RoHS compliant.

2. Dimension



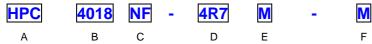




Series	A(mm)	nm) B(mm) C(mm)		D(mm)	E(mm)	
HPC4018NF	4.0±0.2	4.0±0.2	1.8 max.	1.2 ref.	1.6 ref.	

Units: mm

3. Part Numbering



A: Series

B: Dimension

C: Lead Free

D: Inductance

4R7=4.7uH

E: Inductance Tolerance

M=±20% Y=±30%

F::Marking Interpretion 4R7M=4R7 印字:黑色 單向印字

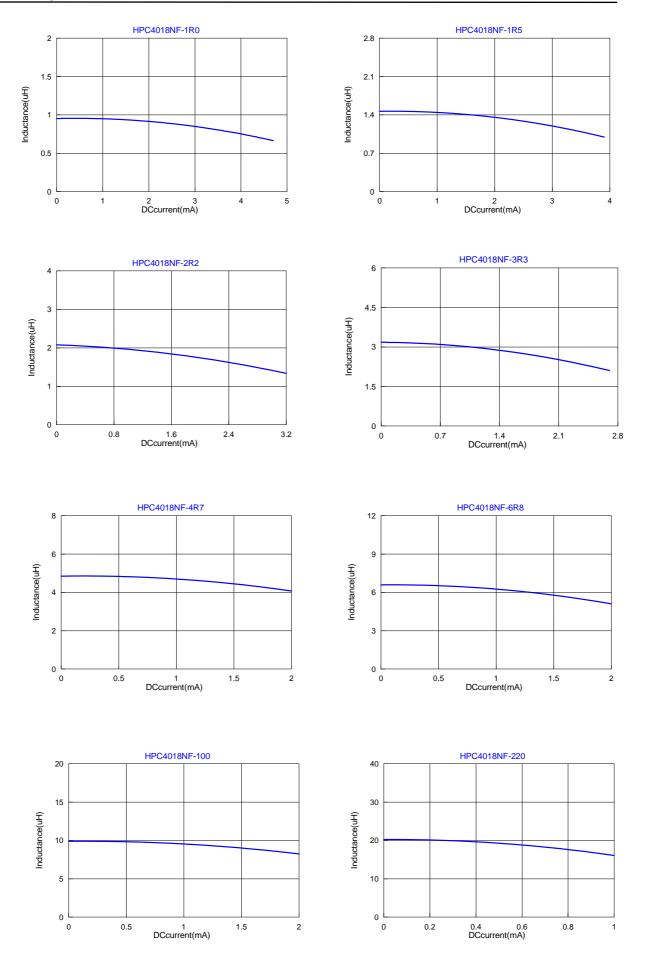
4. Specification

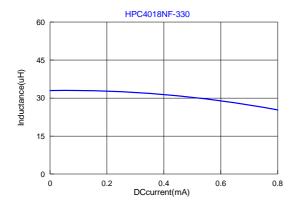
TAI-TECH Part Number	Inductance (uH)	Tolerance (%)	Test Frequency (Hz)	SRF (MHz) typ.	DCR (Ω) ±20%	I sat (A)typ.	I rms (A)typ.
HPC4018NF-1R0Y-M	1.0	±30%	1V100K	160	0.027	4.00	3.50
HPC4018NF-1R5Y-M	1.5	±30%	1V100K	110	0.032	3.30	2.70
HPC4018NF-2R2M-M	2.2	±20%	1V100K	70	0.042	3.00	2.20
HPC4018NF-3R3M-M	3.3	±20%	1V100K	60	0.055	2.30	2.00
HPC4018NF-4R7M-M	4.7	±20%	1V100K	50	0.070	2.00	1.70
HPC4018NF-6R8M-M	6.8	±20%	1V100K	40	0.098	1.60	1.45
HPC4018NF-100M-M	10	±20%	1V100K	35	0.150	1.30	1.20
HPC4018NF-150M-M	15	±20%	1V100K	25	0.210	1.10	0.85
HPC4018NF-220M-M	22	±20%	1V100K	20	0.290	0.90	0.80
HPC4018NF-330M-M	33	±20%	1V100K	12	0.460	0.70	0.55
HPC4018NF-470M-M	47	±20%	1V100K	10	0.650	0.60	0.44

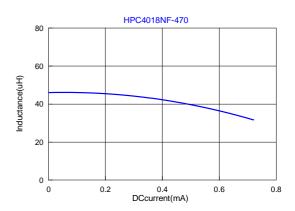
Note:

 $\mbox{Isat}: \mbox{Based on inductance change} \quad (\, \triangle \mbox{L/L0} : \leq 30\% \,) \ \ \mbox{@ ambient temp.} \ \mbox{25} \%$

Irms: Based on temperature rise $(\triangle T : 40^{\circ}C.)$ Max

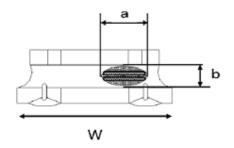






Void appearance tolerance Limit

Size of voids occurring to coating resin is specified below.

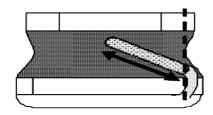


Appearance of exposed wire tolerance limit :

- 1. Width direction (dimension a): Acceptable when $a \le w/2$ Nonconforming when a > w/2
- 2. Length direction (dimension b): Dimension b is not specified.
- 3. The total area of exposed wire occurring to each sides is not greater than 50% of coating resin area, and is acceptable.

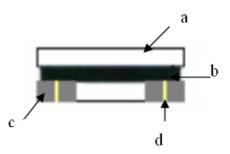
External appearance criterion for exposed wire

Exposed end of the winding wire at the secondary side should be 2mm and below.



5. Material

No.	Description	Specification
a.	Core	Ferrite Core
b.	Glue	Ероху
С	Termination	Tin(Pb Free)
d	Wire	Enameled Copper Wire



6. Reliability and Test Condition

Item	Performance	Test Condition		
Operating temperature	-40~+125℃ (Including self - temperature rise)			
Storage temperature	-40~+125°ℂ (on board)			
Electrical Performance Tes	st			
		HP4284A,CH11025,CH3302,CH1320,CH1320S		
Inductance	Refer to standard electrical characteristics list.	LCR Meter.		
DCR		CH16502,Agilent33420A Micro-Ohm Meter.		
	LL comp. : L	Saturation DC Current (Isat) will cause L0		
Saturation Current (Isat)	△L≦30% typical.	to drop △L(%)(keep quickly).		
		Heat Rated Current (Irms) will cause the coil temperature rise		
Heat Bated Correct (Irres)	Annovirostalu AT < 40%	$\triangle T({}^{\circ}\!$		
Heat Rated Current (Irms)	Approximately △T≤40°C	1.Applied the allowed DC current(keep 1 min.).		
		Z.Temperature measured by digital surface thermometer		
Reliability Test				
		Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles) Temperature: $125\pm2^{\circ}$ C		
Life Test		Applied current : rated current		
		Duration: 1000±12hrs		
Load Humidity		Measured at room temperature after placing for 24±2 hrs Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles Humidity: 85±2*R.H,		
		Temperature: 85°C±2°C		
		Duration: 1000hrs Min. with 100% rated current Measured at room temperature after placing for 24±2 hrs		
		Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles		
Moisture Resistance	Appearance: No damage. Inductance: within±10% of initial value Q: Shall not exceed the specification value. RDC: within±15% of initial value and shall not exceed the specification value	1. Baked at50°C for 25hrs, measured at room temperature after placing for 4 hrs. 2. Raise temperature to $65\pm2^{\circ}\mathbb{C}$ 90-100%RH in 2.5hrs, and keep 3 hours, cool down to $25^{\circ}\mathbb{C}$ in 2.5hrs. 3. Raise temperature to $65\pm2^{\circ}\mathbb{C}$ 90-100%RH in 2.5hrs, and keep 3 hours, cool down to $25^{\circ}\mathbb{C}$ in 2.5hrs,keep at $25^{\circ}\mathbb{C}$ for 2 hrs then keep at -10° \mathbb{C} for 3 hrs 4. Keep at $25^{\circ}\mathbb{C}$ 80-100%RH for 15min and vibrate at the frequency of 10 to 55 Hz to 10 Hz, measure at room temperature after placing for 1–2 hrs.		
Thermal shock		Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles Condition for 1 cycle Step1: -40±2°C 30±5min		
		Step2 : 25±2°C ≤ 0.5min Step3 : 125±2°C 30±5min		
		Number of cycles: 500		
		Measured at room temperature after placing for 24±2 hrs		
VCh madia a		Oscillation Frequency: 10 ~ 2K ~ 10Hz for 20 minutes		
Vibration		Equipment: Vibration checker Total Amplitude:1.52mm±10% Testing Time: 12 hours(20 minutes, 12 cycles each of 3 orientations).		

Item	Performance	Test Condition					
Shock	Appearance: No damage. Inductance: within±10% of initial value	Type Peak value (g' s) Normal duration (D) (ms) Wave form (Vi)ft/sec Velocity change (Vi)ft/sec SMD 50 11 Half-sine 11.3 Lead 50 11 Half-sine 11.3					
Bending	Q : Shall not exceed the specification value. RDC : within ±15% of initial value and shall not exceed the specification value	Shall be mounted on a FR4 substrate of the following dimensions: >=0805:40x100x1.2mm <0805:40x100x0.8mm Bending depth: >=0805:1.2mm <0805:0.8mm duration of 10 sec.					
Soderability	More than 95% of the terminal electrode should be covered with solder.	Preheat: 150°C,60sec.。 Solder: Sn96.5% Ag3% Cu0.5% Temperature: 245±5°C。 Flux for lead free: Rosin. 9.5%。 Dip time: 4±1sec。 Depth: completely cover the termination					
Resistance to Soldering Heat	Appearance: No damage. Inductance: within±10% of initial value Q: Shall not exceed the specification value. RDC: within ±15% of initial value and shall not exceed the specification value	Number of heat cycles: 1 Temperature (°C) Time(s) Temperature ramp/immersion and emersion rate 260 ±5(solder temp) 10 ±1 25mm/s ±6 mm/s					
Terminal Strength		Preconditioning: Run through IR reflow for 2 times.(IPC/JEDEC J-STD-020DClassification Reflow Profiles With the component mounted on a PCB with the device to be tested, apply a force (>0805:1kg , <=0805:0.5kg)to the side of a device being tested. This force shall be applied for 60 +1 seconds. Also the force shall be applied gradually as not to apply a shock to the component being tested.					
		DUT wide substrate press tool					

7. Soldering and Mounting

7-1. Soldering

Mildly activated rosin fluxes are preferred. TAI-TECH terminations are suitable for all wave and re-flow soldering systems. If hand soldering cannot be avoided, the preferred technique is the utilization of hot air soldering tools.

7-1.1 Solder re-flow:

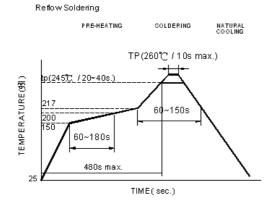
Recommended temperature profiles for re-flow soldering in Figure 1.

7-1.2 Soldering Iron(Figure 2):

Products attachment with a soldering iron is discouraged due to the inherent process control limitations. In the event that a soldering iron must be employed the following precautions are recommended.

- Preheat circuit and products to 150℃
- Never contact the ceramic with the iron tip
- Use a 20 watt soldering iron with tip diameter of 1.0mm

- 355℃ tip temperature (max)
- 1.0mm tip diameter (max)
- Limit soldering time to 4~5 sec.



Reflow times: 3 times max.

Fig.1

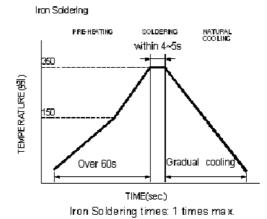
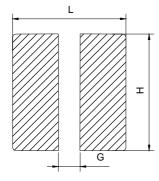


Fig.2

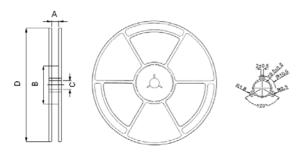
7-2. Recommended PC Board Pattern



L(mm)	G(mm)	H(mm)	
4.2	1.4	4.2	

8. Packaging Information

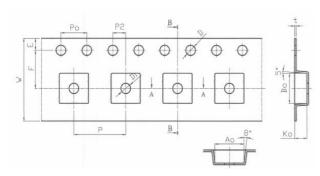
8-1. Reel Dimension



13 "x12mm

Type	A(mm)	A(mm) B(mm)		D(mm)	
13"x12mm	12±1.5	100±0.5	13.2±0.5	330±0.5	

8-2. Tape Dimension / 12mm





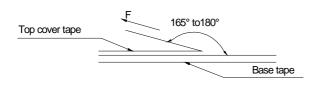
Bottom View

Series	W(mm)	P(mm)	E(mm)	F(mm)	P2(mm)	D(mm)	D1(mm)	P0(mm)	A0(mm)	B0(mm)	K0(mm)	t(mm)
HPC4018	12.00±0.10	8.00±0.10	1.75±0.10	5.50±0.05	2.00±0.05	1.50+0.10/-0.00	1.50±0.10	4.00±0.10	4.50±0.10	4.35±0.10	1.90±0.10	0.25±0.05

8-3. Packaging Quantity

Chip size	4018
Chip / Reel	3500

8-4. Tearing Off Force



The force for tearing off cover tape is 15 to 80 grams in the arrow direction under the following conditions.

Room Temp.	Room Humidity	Room atm	Tearing Speed
(℃)	(%)	(hPa)	mm/min
5~35	45~85	860~1060	300

Application Notice

- Storage Conditions(component level)
- To maintain the solderability of terminal electrodes:
- 1. TAI-TECH products meet IPC/JEDEC J-STD-020D standard-MSL, level 1.
- 3. Recommended products should be used within 12 months form the time of delivery.
- 4. The packaging material should be kept where no chlorine or sulfur exists in the air.
- Transportation
 - 1. Products should be handled with care to avoid damage or contamination from perspiration and skin oils.
- $2. \ The \ use of \ tweezers \ or \ vacuum \ pick \ up \ is \ strongly \ recommended \ for \ individual \ components.$
- 3. Bulk handling should ensure that abrasion and mechanical shock are minimized.



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頁數(Page): 1 of 15

Test Report

西北臺慶科技股份有限公司 / TAI-TECH ADVANCED ELECTRONICS CO., LTD.

DOMESTICATION OF BUILDING

(臺慶精密電子(昆山)有限公司 / TAI-TECH ADVANCED ELECTRONICS (KUN-SHAN) CO. LTD.)

(耀鑚科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)

(慶邦電子元器件 (泗洪) 有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.)

桃園市楊梅區幼獅工業區幼四路1號 / NO. 1, YOU 4TH ROAD, YOUTH INDUSTRIAL DISTRICT, YANG-MEI, TAO-YUAN CITY, TAIWAN, R.O.C. (江蘇省昆山市篷朗昆嘉高科技工業區郭澤路 / GUO-ZE ROAD, KUNJIA HI-TECH INDUSTRIAL PARK, KUN-SHAN, JIANG-SU, CHINA) (桃園市中壢區中壢工業區長春六路15號 / NO. 15, CHANGCHUN 6TH RD., JHONGLI CITY, TAOYUAN COUNTY 320, TAIWAN) (江蘇省宿遷市泗洪縣經濟開發區金沙南路-高新技術產業園 / HIGH-TECH INDUSTRIAL DISTRICT, JINSHAJIANG ROAD, SIHONG COUNTY ECONOMIC, SUQIAN CITY, JIANGSU)

以下測試樣品係由申請廠商所提供及確認 (The following sample(s) was/were submitted and identified by/on behalf of the applicant as):

樣品名稱(Sample Description)

SMD POWER INDUCTOR

樣品型號(Style/Item No.)

HPC(YHC · DR) · MDC · FPC(YPC) · FWP(YWP) · SPC · AHP · UHP · DFP · DHP · TLPC ·

TLPH . TLI SERIES

收件日期(Sample Receiving Date)

2015/11/10

測試期間(Testing Period)

2015/11/10 TO 2015/11/16

測試結果(Test Results) :

請見下一頁 (Please refer to next pages).

Troy Chang Manage Signed for and on Deha SGS TAIWAN LTD Chemical Laboratory - Taipei

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日期(Date): 2015/11/16

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測試結果(Test Results)

測試部位(PART NAME)No.1

整體混測 (MIXED ALL PARTS)

測試項目 (Test Items)	單位 (Unit)			結果 (Result)
(Test Teems)	(onit)	(mo chody	(MDL)	No. 1
鎬 / Cadmium (Cd)	mg/kg	參考IEC 62321-5: 2013方法, 以感應耦合 電漿原子發射光譜儀檢測. / With reference to IEC 62321-5: 2013 and performed by ICP-AES.	2	n. d.
鉛 / Lead (Pb)	mg/kg	參考IEC 62321-5: 2013方法, 以感應耦合 電漿原子發射光譜儀檢測. / With reference to IEC 62321-5: 2013 and performed by ICP-AES.	2	n. d.
汞 / Mercury (Hg)	mg/kg	參考IEC 62321-4: 2013方法, 以感應耦合 電漿原子發射光譜儀檢測. / With reference to IEC 62321-4: 2013 and performed by ICP-AES.	2	n. d.
六價鉻 / Hexavalent Chromium Cr(VI)	mg/kg	參考IEC 62321: 2008方法,以UV-VIS檢測. / With reference to IEC 62321: 2008 and performed by UV-VIS.	2	n. d.
六溴環十二烷及所有主要被辨別出的異構物 / Hexabromocyclododecane (HBCDD) and all major diastereoisomers identified (α - HBCDD, β - HBCDD, γ - HBCDD) (CAS No.: 25637-99-4 and 3194-55-6 (134237-51-7, 134237-50-6, 134237-52-8))	mg/kg	參考IEC 62321: 2008方法,以氣相層析/質譜儀檢測. / With reference to IEC 62321: 2008 method. Analysis was performed by GC/MS.	5	n. d.

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測試項目 (Test Items)	單位 (Unit)	測試方法 (Method)	方法偵測 極限值 (MDL)	結果 (Result)
				No. 1
聚氯乙烯 / PVC	**	以紅外光譜分析及焰色法檢測. / Analysis was performed by FTIR and FLAME Test.	122	Negative
多溴聯苯總和 / Sum of PBBs	mg/kg		2	n. d.
一溴聯苯 / Monobromobiphenyl	mg/kg		5	n. d.
二溴聯苯 / Dibromobiphenyl	mg/kg		5	n. d.
三溴聯苯 / Tribromobiphenyl	mg/kg		5	n. d.
四溴聯苯 / Tetrabromobiphenyl	mg/kg] - [5	n. d.
五溴聯苯 / Pentabromobiphenyl	mg/kg]	5	n. d.
六溴聯苯 / Hexabromobiphenyl	mg/kg] [5	n. d.
七溴聯苯 / Heptabromobiphenyl	mg/kg	参考IEC 62321-6: 2015方法,以氣相層析/ 質譜儀檢測. / With reference to IEC -62321-6: 2015 and performed by GC/MS.	5	n. d.
八溴聯苯 / Octabromobiphenyl	mg/kg		5	n. d.
九溴聯苯 / Nonabromobiphenyl	mg/kg		5	n. d.
十溴聯苯 / Decabromobiphenyl	mg/kg		5	n. d.
多溴聯苯醚總和 / Sum of PBDEs	mg/kg			n. d.
一溴聯苯醚 / Monobromodiphenyl ether	mg/kg		5	n. d.
二溴聯苯醚 / Dibromodiphenyl ether	mg/kg] [5	n. d.
三溴聯苯醚 / Tribromodiphenyl ether	mg/kg]	5	n. d.
四溴聯苯醚 / Tetrabromodiphenyl ether	mg/kg		5	n. d.
五溴聯苯醚 / Pentabromodiphenyl ether	mg/kg		5	n. d.
六溴聯苯醚 / Hexabromodiphenyl ether	mg/kg		5	n. d.
七溴聯苯醚 / Heptabromodiphenyl ether	mg/kg		5	n. d.
八溴聯苯醚 / Octabromodiphenyl ether	mg/kg		5	n. d.
九溴聯苯醚 / Nonabromodiphenyl ether	mg/kg		5	n. d.
十溴聯苯醚 / Decabromodiphenyl ether	mg/kg		5	n. d.

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(耀鑽科技股份有限公司 / YOSONIC TECHNOLOGY CO., LTD.)

(慶邦電子元器件 (泗洪) 有限公司 / TAIPAQ ELECTRONICS (SI-HONG) CO., LTD.)

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測試項目 (Test Items)	單位 (Unit)	測試方法 (Method)	方法偵測 極限值 (MDL)	結果 (Result)
				No. 1
錦 / Antimony (Sb)	mg/kg	參考US EPA 3052方法,以感應耦合電漿原子發射光譜儀檢測. / With reference to US EPA Method 3052. Analysis was performed by ICP-AES.	2	n. d.
鈹 / Beryllium (Be)	mg/kg	參考US EPA 3052方法,以感應耦合電漿原 子發射光譜儀檢測. / With reference to US EPA Method 3052. Analysis was performed by ICP-AES.	2	n. d.
全氟辛烷磺酸 / Perfluorooctane sulfonates (PFOS-Acid, Metal Salt, Amide)	mg/kg	參考US EPA 3550C: 2007方法, 以液相層析 /質譜儀檢測. / With reference to US EPA 3550C: 2007. Analysis was performed by LC/MS.	10	n. d.
全氟辛酸 / PFOA (CAS No.: 335-67-1)	mg/kg	参考US EPA 3550C: 2007方法, 以液相層析 /質譜儀檢測. / With reference to US EPA 3550C: 2007. Analysis was performed by LC/MS.	10	n. d.
鹵素 / Halogen				
鹵素(氣)/ Halogen-Fluorine (F) (CAS No.: 14762-94-8)	mg/kg	2	50	n. d.
鹵素(氣)/ Halogen-Chlorine (C1) (CAS No.: 22537-15-1)	mg/kg	参考BS EN 14582:2007, 以離子層析儀分析. / With reference to BS EN	50	n. d.
鹵素(溴)/ Halogen-Bromine (Br) (CAS No.: 10097-32-2)	mg/kg	14582:2007. Analysis was performed by IC.	50	n. d.
鹵素 (碘) / Halogen-Iodine (I) (CAS No.: 14362-44-8)	mg/kg		50	n. d.

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測試項目 (Test Items)	單位 (Unit)	測試方法 (Method)	方法偵測 極限值 (MDL)	結果 (Result) No.1
鄭苯二甲酸丁苯甲酯 / BBP (Butyl Benzyl phthalate) (CAS No.: 85-68-7)	mg/kg		50	n. d.
鄰苯二甲酸二丁酯 / DBP (Dibutyl phthalate) (CAS No.: 84-74-2)	mg/kg	参考IEC 62321-8 (111/321/CD),以氣相層 析儀/質譜儀檢測之. / With reference to IEC 62321-8 (111/321/CD). Analysis was performed by GC/MS.	50	n. d.
鄰苯二甲酸二 (2-乙基己基)酯 / DEHP (Di- (2-ethylhexyl) phthalate) (CAS No.: 117-81-7)	mg/kg		50	n. d.
鄰苯二甲酸二異丁酯 / DIBP (Di- isobutyl phthalate) (CAS No.: 84-69- 5)	mg/kg		50	n. d.
鄰苯二甲酸二異癸酯 / DIDP (Di- isodecyl phthalate) (CAS No.: 26761- 40-0; 68515-49-1)	mg/kg		50	n. d.
鄰苯二甲酸二異壬酯 / DINP (Di- isononyl phthalate) (CAS No.: 28553- 12-0; 68515-48-0)	mg/kg		50	n. d.
鄰苯二甲酸二正辛酯 / DNOP (Di-n- octyl phthalate) (CAS No.: 117-84-0)	mg/kg		50	n. d.
鄰苯二甲酸二正己酯 / DNHP (Di-n- hexyl phthalate) (CAS No.: 84-75-3)	mg/kg		50	n. d.

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備註(Note):

- 1. mg/kg = ppm ; 0.1wt% = 1000ppm
- 2. n.d. = Not Detected (未檢出)
- 3. MDL = Method Detection Limit (方法偵測極限值)
- 4. "-" = Not Regulated (無規格值)
- 5. **= Qualitative analysis (No Unit) 定性分析(無單位)
- 6. Negative = Undetectable 陰性(未偵測到); Positive = Detectable 陽性(已偵測到)
- 7. 樣品的測試是基於申請人要求混合測試,報告中的混合測試結果不代表其中個別單一材質的含量. (The samples was/were analyzed on behalf of the applicant as mixing sample in one testing. The above results was/were only given as the informality value.)

PFOS參考資訊(Reference Information): 持久性有機污染物 POPs - (EU) 757/2010

PFOS濃度在物質或製備中不得超過0.001%(10ppm),在半成品、成品或零部件中不得超過0.1%(1000ppm),在紡織品或塗 層材料中不得超過1µg/m²。

(Outlawing PFOS as substances or preparations in concentrations above 0.001% (10ppm), in semi-finished products or articles or parts at a level above 0.1%(1000ppm), in textiles or other coated materials above $1\mu g/m^2$.)

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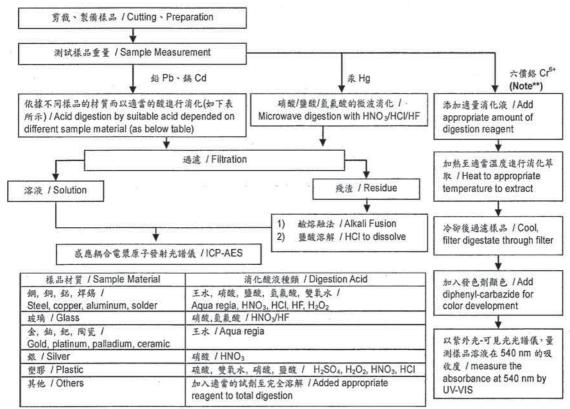
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- 根據以下的流程圖之條件,樣品已完全溶解。(六價絡測試方法除外) / These samples were dissolved totally by pre-conditioning method according to below flow chart. (Cr⁶⁺ test method excluded)
- 2) 测試人員:楊登偉 / Name of the person who made measurement: Climbgreat Yang
- 3) 测試負責人:張啟興 / Name of the person in charge of measurement: Troy Chang



Note** (For IEC 62321)

- (1) 針對非金屬材料加入鹼性消化液 · 加熱至 90~95℃ 萃取. / For non-metallic material, add alkaline digestion reagent and heat to 90~95℃.
- (2) 針對金屬材料加入純水,加熱至沸騰萃取. / For metallic material, add pure water and heat to boiling.

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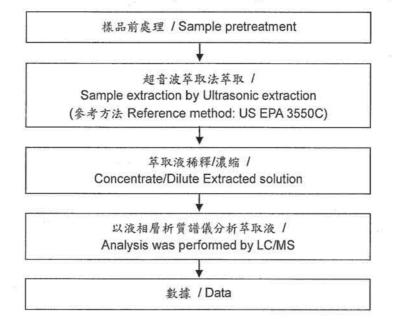
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全氟辛酸/全氟辛烷磺酸分析流程圖 / PFOA/PFOS analytical flow chart

- 測試人員: 翁賜彬 / Name of the person who made measurement: Roman Wong
- 測試負責人: 張啟興 / Name of the person in charge of measurement: Troy Chang



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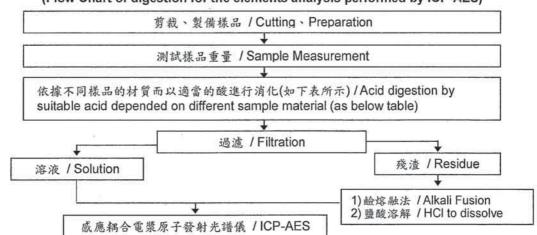
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- 根據以下的流程圖之條件,樣品已完全溶解。 / These samples were dissolved totally by pre-conditioning method according to below flow chart.
- 測試人員:楊登偉 / Name of the person who made measurement: Climbgreat Yang
- 測試負責人:張啟興 / Name of the person in charge of measurement: Troy Chang

元素以 ICP-AES 分析的消化流程圖 (Flow Chart of digestion for the elements analysis performed by ICP-AES)



鋼,銅,鋁,焊錫 / Steel, copper, aluminum, solder	王水,硝酸,鹽酸,氫氟酸,雙氧水 / Aqua regia, HNO ₃ , HCI, HF, H ₂ O ₂
玻璃 / Glass	硝酸,氫氟酸 / HNO ₃ /HF
金,鉑,鉋,陶瓷 / Gold, platinum, palladium, ceramic	王水 / Aqua regia
銀 / Silver	硝酸 / HNO ₃
塑膠 / Plastic	硫酸,雙氧水,硝酸,鹽酸 / H ₂ SO ₄ , H ₂ O ₂ , HNO ₃ , HCI
其他 / Others	加入適當的試劑至完全溶解 / Added appropriate reagent to total digestion

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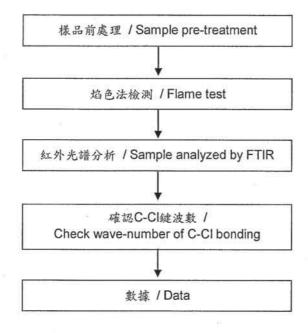
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聚氯乙烯物質判定分析流程圖 /

Analysis flow chart for determination of PVC in material

- 測試人員: 林建宇 / Name of the person who made measurement: Roy Lin
- 測試負責人: 張啟興 / Name of the person in charge of measurement: Troy Chang



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WEI AFORE EXHIBITE

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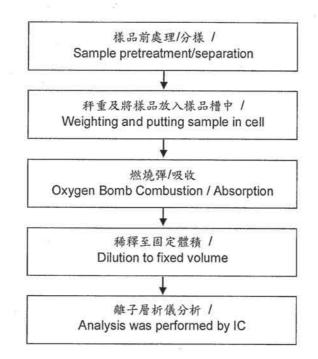
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鹵素分析流程圖 / Analytical flow chart of halogen content

- 測試人員: 陳恩臻 / Name of the person who made measurement. Rita Chen
- 測試負責人: 張啟興 / Name of the person in charge of measurement: Troy Chang



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六溴環十二烷分析流程圖 / HBCDD analytical flow chart

- 測試人員: 翁賜彬 / Name of the person who made measurement: Roman Wong
- 測試負責人:張啟興 / Name of the person in charge of measurement: Troy Chang



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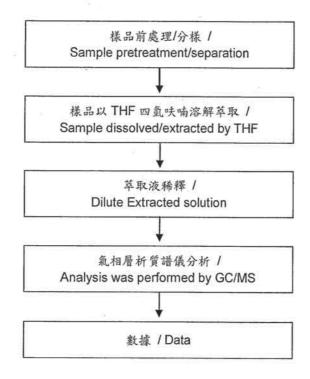
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可塑劑分析流程圖 / Analytical flow chart of phthalate content

- 測試人員: 徐毓明 / Name of the person who made measurement: Andy Shu
- 測試負責人: 張啟興 / Name of the person in charge of measurement: Troy Chang

【測試方法/Test method: IEC 62321-8】



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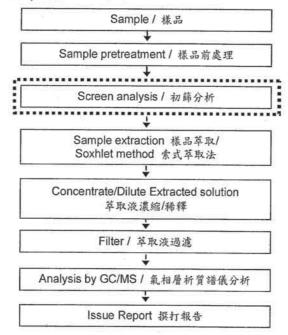
多溴聯苯/多溴聯苯醚分析流程圖 / PBB/PBDE analytical FLOW CHART

- 測試人員: 翁賜彬 / Name of the person who made measurement: Roman Wong
- 測試負責人: 張啟興 / Name of the person in charge of measurement: Troy Chang

初次測試程序 / First testing process -

選擇性篩檢程序 / Optional screen process *******

確認程序 / Confirmation process - · - · ▶



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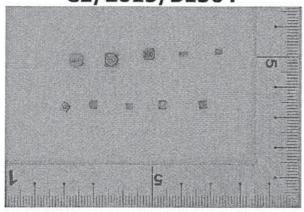
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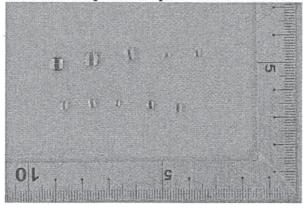
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* 照片中如有箭頭標示,則表示為實際檢測之樣品/部位. * (The tested sample / part is marked by an arrow if it's shown on the photo.)

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** 報告結尾 (End of Report) **

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